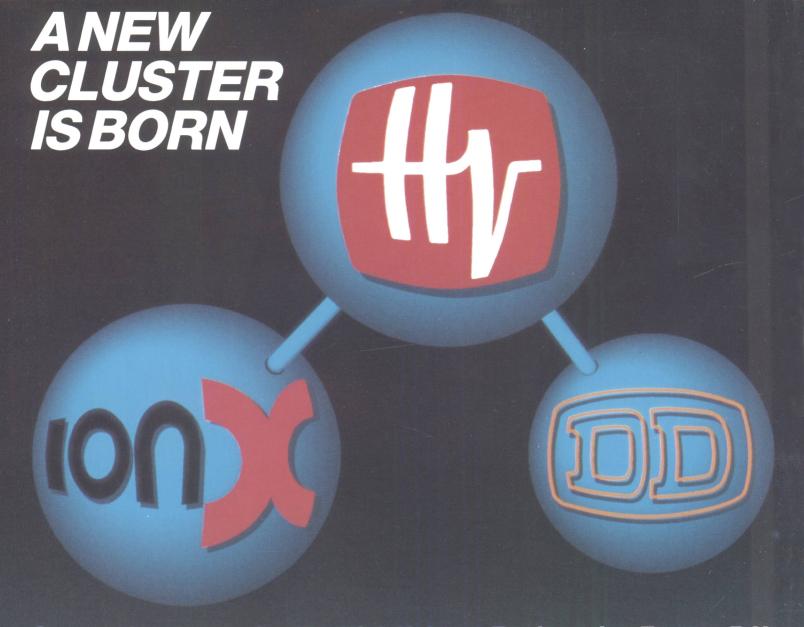
# MRS BULLETIN

December 1989

Volume XIV, Number 12

**Serving the International Materials Research Community** 





## General Ionex acquired by High Voltage Engineering Europa B.V.

In December 1987 High Voltage Engineering Europa B.V. (HVEE) acquired Dowlish Developments Ltd (DD), an accelerator tube manufacturer located in the United Kingdom.

On April 10, 1989, HVEE purchased the General Ionex Analytical Product Group from Genus Inc. based in the United

Through this acquisition HVEE positions itself as the largest and most diverse manufacturer of particle accelerators for the scientific and industrial research communities.

The acquired General Ionex (GI) product lines, which include the Tandetron accelerator systems and Model 4175 RBS Analyser, will be manufactured in HVEE's new, well-equipped facility in Amersfoort, The Netherlands.

World wide marketing of all products from HVEE, DD and GI will originate from HVEE Amersfoort with sales and service offices in the USA, Europe and Japan.

After addition of the newly acquired products HVEE's product lines include:

- Ion Accelerator Systems
  - Air insulated accelerators up to 500 kV
  - Single ended Van de Graaff accelerators up to 4 MV
  - Tandem Tandetron accelerators up to 3 MV/TV
- Research ion implanters
  - Beam energies 10 keV-9 MeV and higher
- Systems for ion beam analysis
  - Systems for RBS, PIXE, PIGE, NRA, ERD, MACS and MEIS
- Components
  - HV power supplies, electron and ion accelerator tubes, ion sources beamline components, beam monitoring equipment, UHV sample manipulators, etc.

For further information on this transaction and product literature please contact HVEE in Amersfoort/NL.



#### HIGH VOLTAGE ENGINEERING EUROPA B.V.

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# FINE PARTICLES Part I

- 18 Fine Particles: Science and Technology
  - E. Matijević, Guest Editor
- Preparation and Characterization of Monodispersed Colloidal Particles
  - T. Sugimoto
- 29 Preparing Monodisperse
  Metal Powders in Micrometer and Submicrometer
  Sizes by the Polyol Process

F. Fievet, J.P. Lagier, and M. Figlarz

35 Preparation and Properties of Well-Defined Magnetic Particles

M. Ozaki

41 Preparing Narrow Size
Distribution Particles from
Amphiphilic Association
Structures

A.J.I. Ward and S. Friberg

## **SPECIAL FEATURE**

49 Excimer Laser Drill for Multilayer Printed Circuit Boards: From Advanced Development to Factory Floor

F. Bachmann

### <u>ISSUES</u>

47 GM Research Labs Host AIP Corporate Associates, OSTP Director Bromley is Keynote Speaker

#### **INTERNATIONAL**

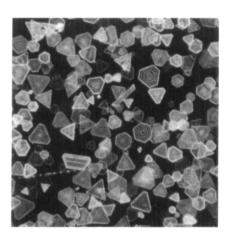
48 European Networks Focus on Advanced Materials

### **MRS NEWS**

- 54 Hull, McCarthy, and Spaepen Are 1990 MRS Fall Meeting Chairs
- 56 Candidates Sought for Graduate Student Awards at 1990 MRS Spring Meeting

#### **DEPARTMENTS**

- 4 Letter from the President
- 7 Material Matters
- 9 Research/Researchers
- 14 Research Resources
- 15 Editor's Choice
- 16 From Washington
- **56** Short Course News
- **58** Section News
- **58** Chapter News
- **60** Upcoming Conferences
- **63** Historical Note
- 65 Book Reviews
- 67 Calendar
- 70 Classified
- 72 Advertisers in this Issue



ON THE COVER: This unique photomicrograph was taken using a recently designed lowtemperature (-196 °C) luminescence microscope (*J. Imaging Science*, **32**, 1988, p. 15). By banding a silver bromide tabular grain emulsion during growth with low levels of iodide, luminescence patterns were created which reveal the growth histories of the individual crystals, somewhat analogous to the growth rings of trees. This technique showed, for the first time, the variety of mechanisms by which these ( $\sim$ 10  $\mu$ m) AgBr tabular crystals grew (*J. Imaging Science*, **31**, 1987, p. 15). The sample was exposed to ultraviolet light and its luminescence was recorded using 40 seconds on Kodacolor VR200 film. (Photo courtesy of J.E. Markasky, author of the procedure, Eastman Kodak Company.) For more on the development and analysis of fine particles, see the series of articles beginning on p. 18 in this issue.

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The Society's interdisciplinary approach to the exchange of technical information is qualitatively different from that provided by single-discipline professional societies because it promotes technical exchange across the various fields of science affecting materials development. MRS sponsors two major international annual meetings encompassing approximately 30 topical symposia, as well as numerous single-topic scientific meetings each year. It recognizes professional and technical excellence, conducts short courses, and fosters technical exchange in various local geographic regions through Section activities and University Chapters.

MRS is an Affiliated Society of the American Institute of Physics and participates in the international arena of materials research through associations with professional organizations such as European MRS.

MRS publishes symposium proceedings, the MRS BULLETIN, Journal of Materials Research, and other current scientific developments.

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